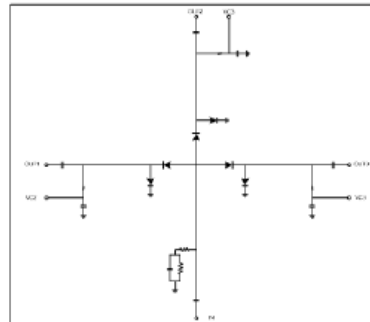


**Features**

- Frequency: 10-40GHz
- Insertion Loss: 0.7dB typ.
- Isolation: 41dB typ.
- P-1dB: 25dBm
- Input/Output: 50Ω
- Die Size: 1.92x 1.57x 0.1 mm

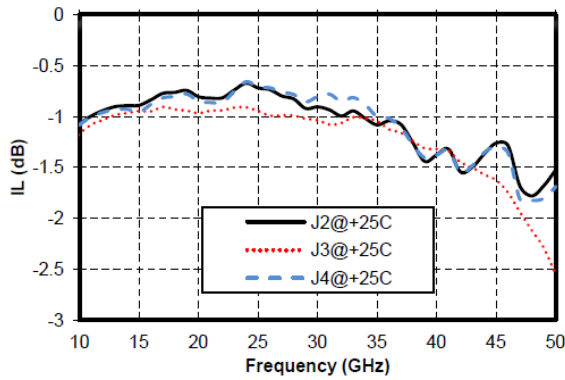
**Typical Applications**

- Test Instrumentation
- Microwave Radio & VSAT
- Military & Space
- Telecom Infrastructure
- Fiber Optics

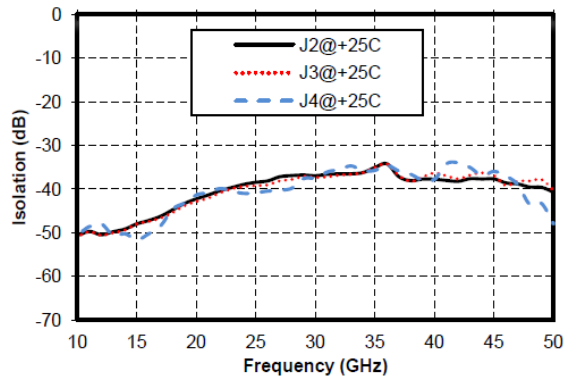
**Functional Block Diagram**

**Electrical Specifications**
**TA = +25°C**

Parameters	Min.	Typ.	Max.	Units
Frequency Range	10-40			GHz
Insertion Loss	-	0.7	1.4	dB
Isolation	37	41	-	dB
Input Return Loss	14	15	-	dB
Output Return Loss	12	19	-	dB
P-1dB	-	25	-	dBm
Switching Speed	-	20	-	ns

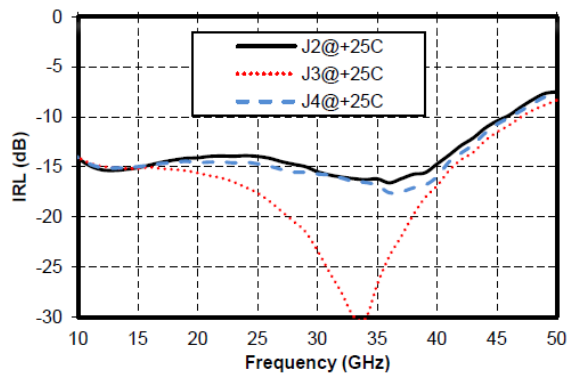
**Insertion Loss vs. Operating Frequency**



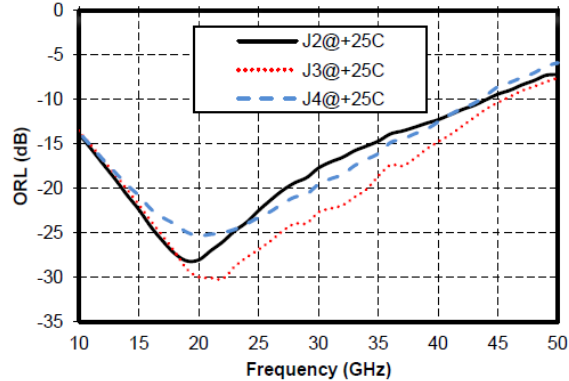
**Isolation vs. Operating Frequency**



**Input Return Loss vs. Operating Frequency**



**Output Return Loss vs. Operating Frequency**



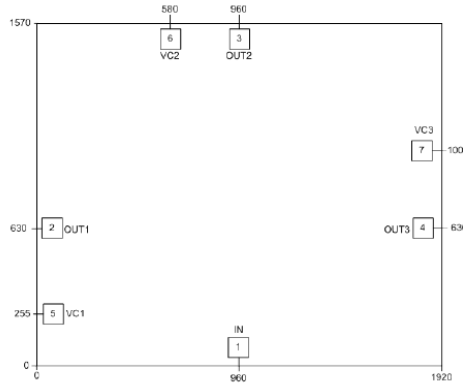
Typical Driver Connections

CONTROL LEVEL (DC CURRENT)			RF OUTPUT STATE		
VC1	VC2	VC3	OUT1(J2)-IN(J1)	OUT2(J3)-IN(J1)	OUT3(J4)-IN(J1)
-10mA	+10mA	+10mA	Low Loss	Isolation	Isolation
+10mA	-10mA	+10mA	Isolation	Low Loss	Isolation
+10mA	+10mA	-10mA	Isolation	Isolation	Low Loss



### Outline Drawing

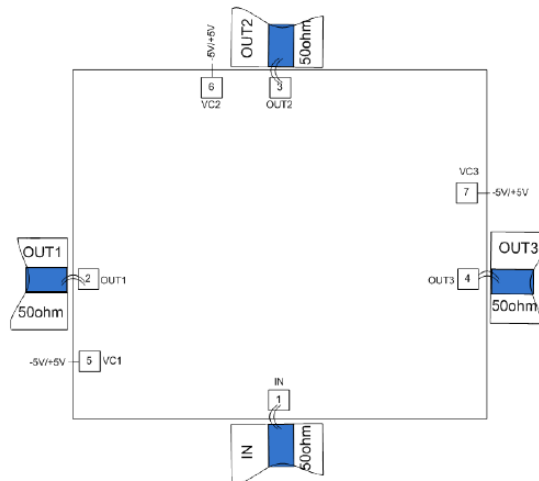
All Dimensions in  $\mu\text{m}$



### Pad Description

Pad	Function	Description
1	IN(J1)	RF signal input port
2,3,4	OUT1(J2), OUT2(J3), OUT3(J4)	RF signal output port
5,6,7	VC1, VC2, VC3	Signal control port
Die bottom	GND	Die bottom must be connected to RF/DC ground.

### Assembly Drawing



#### Notes:

1. Die thickness: 100 $\mu\text{m}$
2. Typical bond pad is 100\*100  $\mu\text{m}^2$
3. Bond pad metalization: Gold
4. Backside metalization: Gold
5. Backside of the die (GND)
6. No connection required for unlabeled bond pads

#### Maximum Ratings:

1. Maximum input voltage: 25V
2. Maximum input power: +31dBm CW
3. Operating temperature: -55 $^{\circ}\text{C}$  to +85 $^{\circ}\text{C}$
4. Storage temperature: -65 $^{\circ}\text{C}$  to +150 $^{\circ}\text{C}$